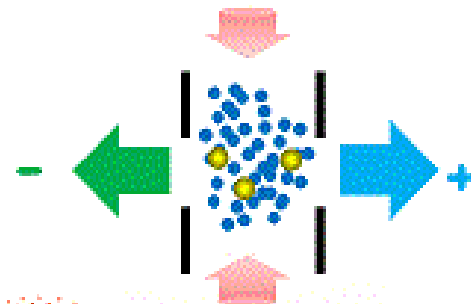
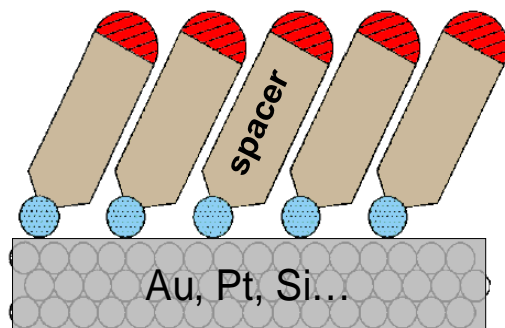


# Low-energy (0-20 eV) Electron Beam for Chemical Control in Surface Modification (for chemically controlled modification of supported organic films)

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Institut des Sciences Moléculaires d'Orsay - ISMO  
CNRS - Université Paris-Sud, Orsay, France



# Contents

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Motivations & model aromatic SAMs

Low-energy (0-20 eV) electron induced dissociative processes  
Experimental procedure using a very rustic electron gun...

## Terphenylthiol SAMs

Identification of an electron attachment resonance at 6 eV

Electron processing

induced chemical modification

involved mechanisms

Conclusions & Perspectives

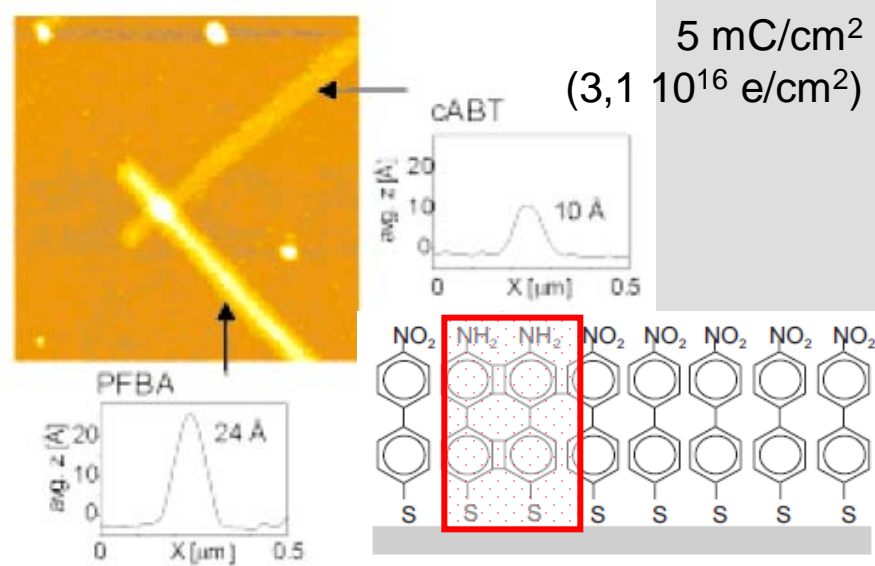
# Electron processing for structuration of substrates

Development of molecular platforms for chemical or biological devices  
 Response to irradiation (standard probing techniques & lithography) of resist materials (contrast, sensitivity, defects)

Cyganik J.Phys.Chem.B 2005

Heister Langmuir 2000

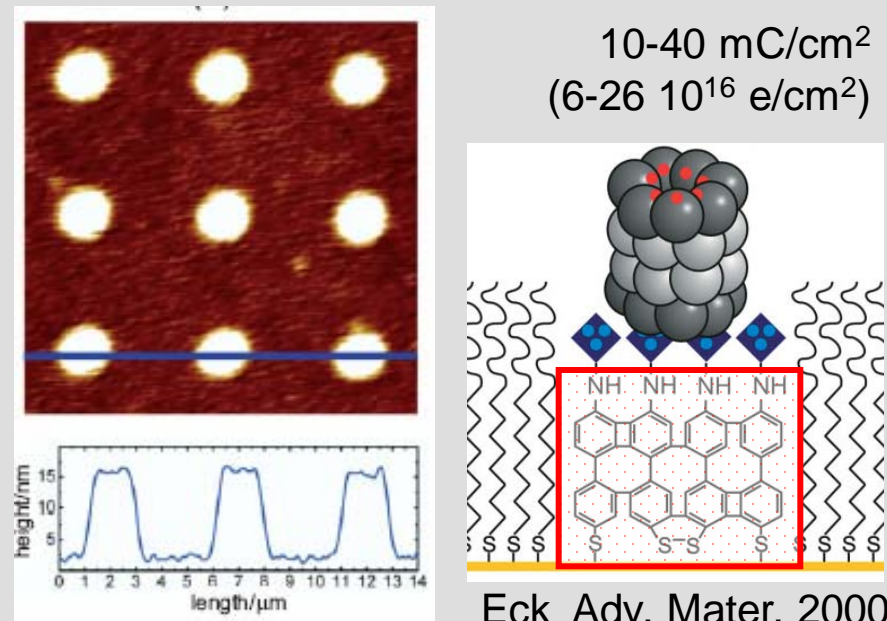
At high energy (2-20 keV)  
 Electron microscope (EBL)  
 Nanometer scale (20-200 nm)



Gölzhäuser Adv. Mat. 2001

Ballav AngewChem 2008, JPhysChem 2007

At low energy (~50-100 eV)  
 Electron irradiation through masks  
 Micrometer scale (2 μm)

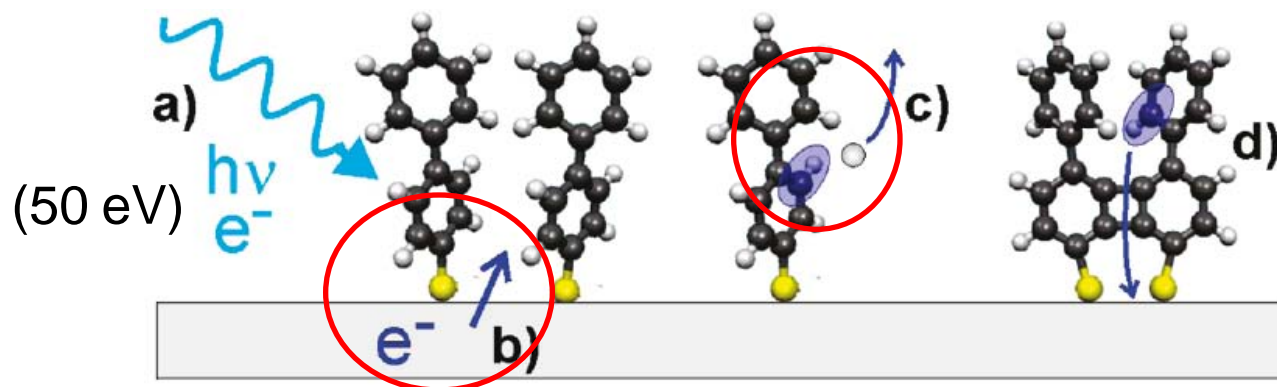


Eck Adv. Mater. 2000

Turchanin Adv. Mater. 2008

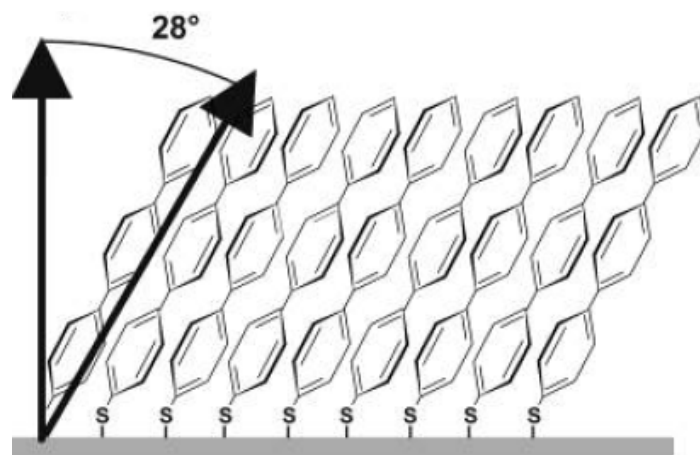
# Stabilization by cross-linking & Model aromatic SAM

Aromatic SAMs - **Improved stability** by irradiation induced cross-linking  
Among the proposed mechanisms: secondary electron induced chemistry



Turchanin  
Langmuir 2009

## Terphenylthiol (TPT) on gold



V. Humblot  
C.-M. Pradier

UPMC  
PARIS UNIVERSITÉS

LABORATOIRE  
DE RÉACTIVITÉ  
DE SURFACE  
LRS  
PARIS

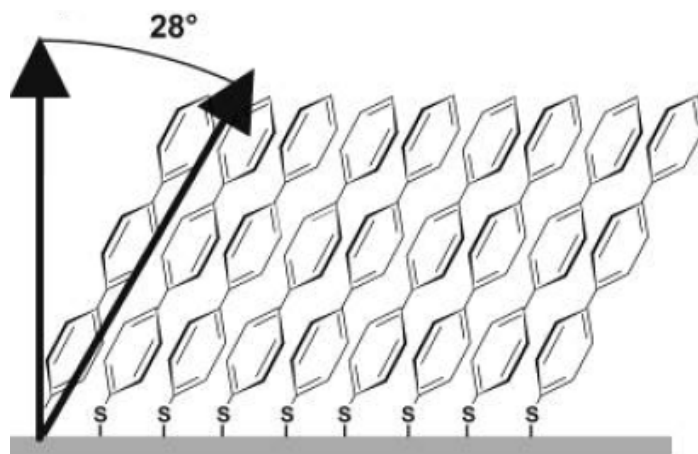
Frey Langmuir 2001 /  
Fuxen Langmuir 2001

UNIVERSITÉ  
PARIS  
SUD

# Stabilization by cross-linking & Model aromatic SAM

- To investigate the contribution of low-energy 2<sup>nd</sup> electrons to the modifications induced within the supported molecular layer
- To understand the primary interaction mechanisms of low-energy electrons with film of molecular species
- To control and orientate per electron irradiation the chemistry induced in the supported interface and at the substrate surface

## Terphenylthiol (TPT) on gold



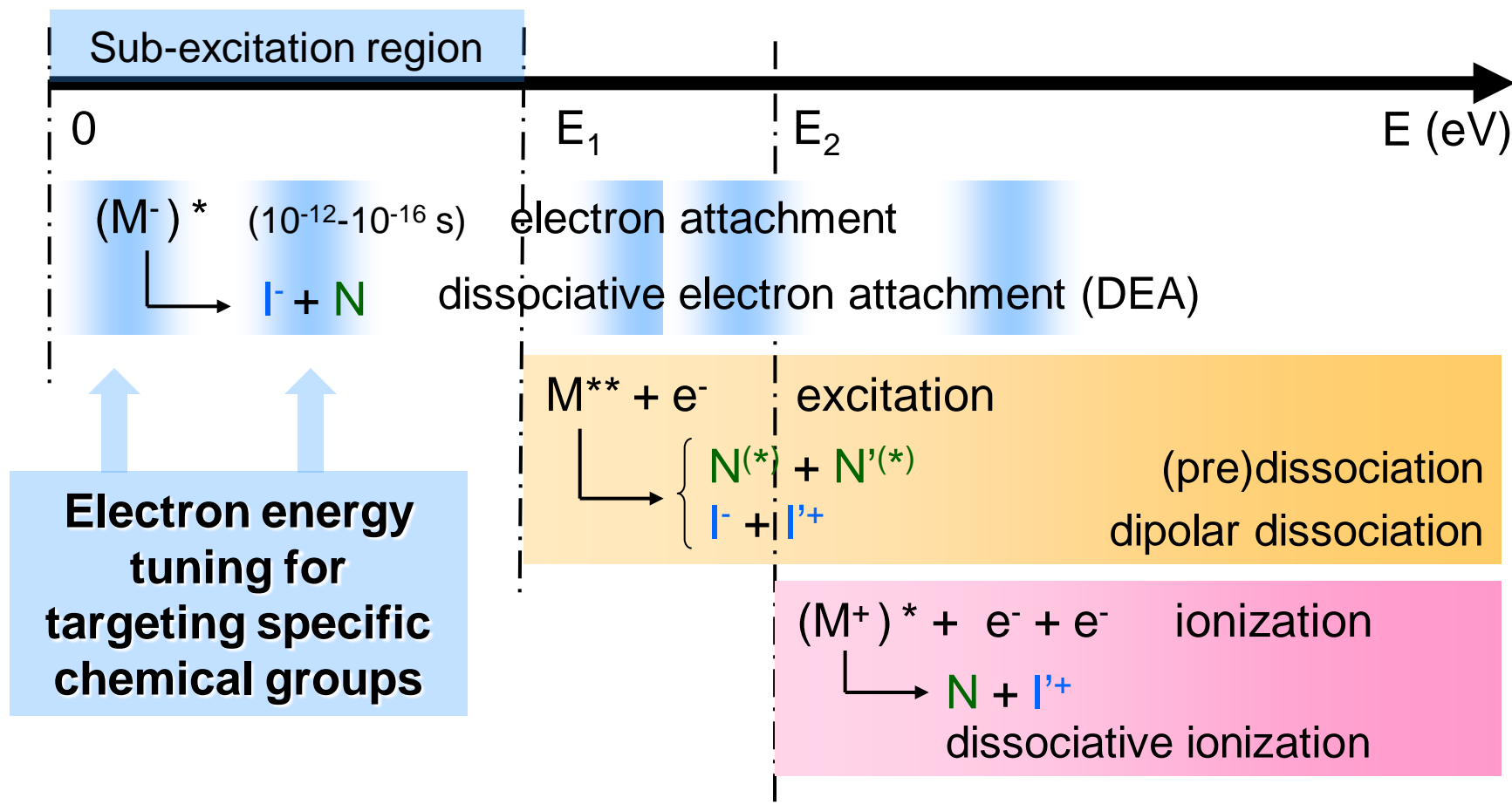
V. Humblot  
C.-M. Pradier

UPMC  
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LABORATOIRE  
DE RÉACTIVITÉ  
DE SURFACE  
LRS  
PARIS

Frey Langmuir 2001 /  
Fuxen Langmuir 2001

# $e^- + M$ – Dissociative processes induced by electron impact



G.J. Schulz Rev. Modern Phys. 1973

COLDBEAMS, Nîmes, October 2012

E. Illenberger, in Adv. Series in Phys.Chem10B 2000

I. Bald Int. J. Mass Spectrom. 2008

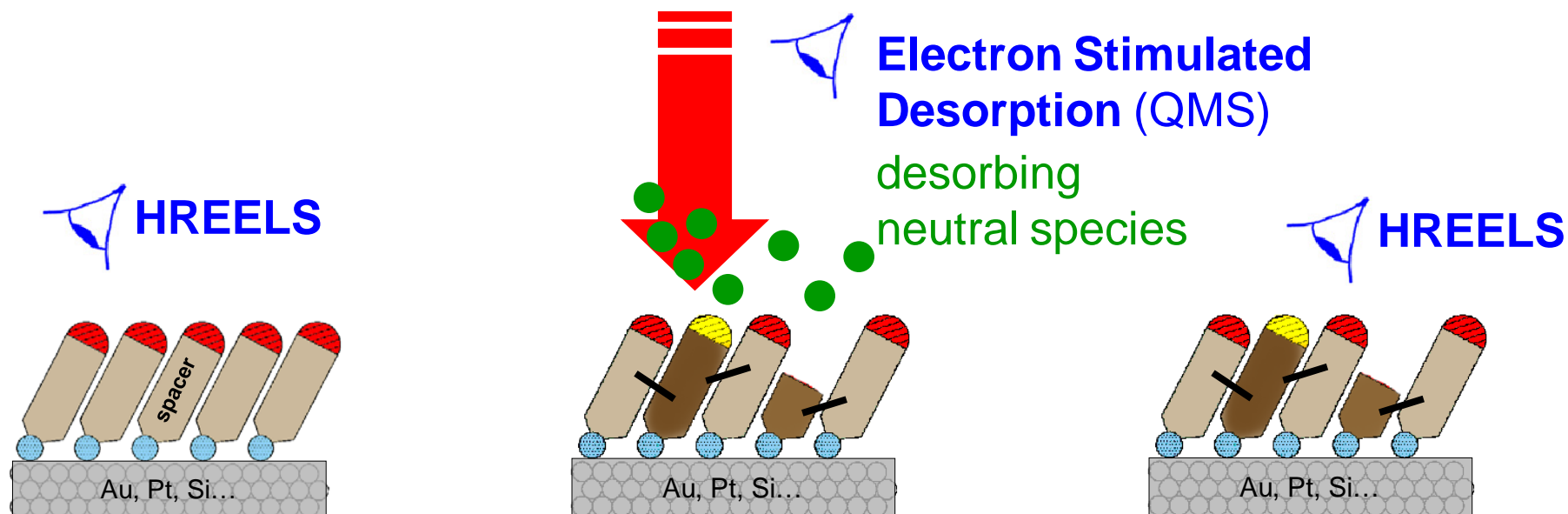
# Experimental procedure - Induced chemistry at RT in UHV

Low-energy electron PROCESSING

Commercial electron gun

$E \sim 0.5\text{-}20\text{ eV}$     $\varnothing \sim 2\text{-}7\text{ mm}$     $I \sim 0,02 - 1,60\ \mu\text{A}$

$D \sim 30\text{-}500\text{ e/molecule}$



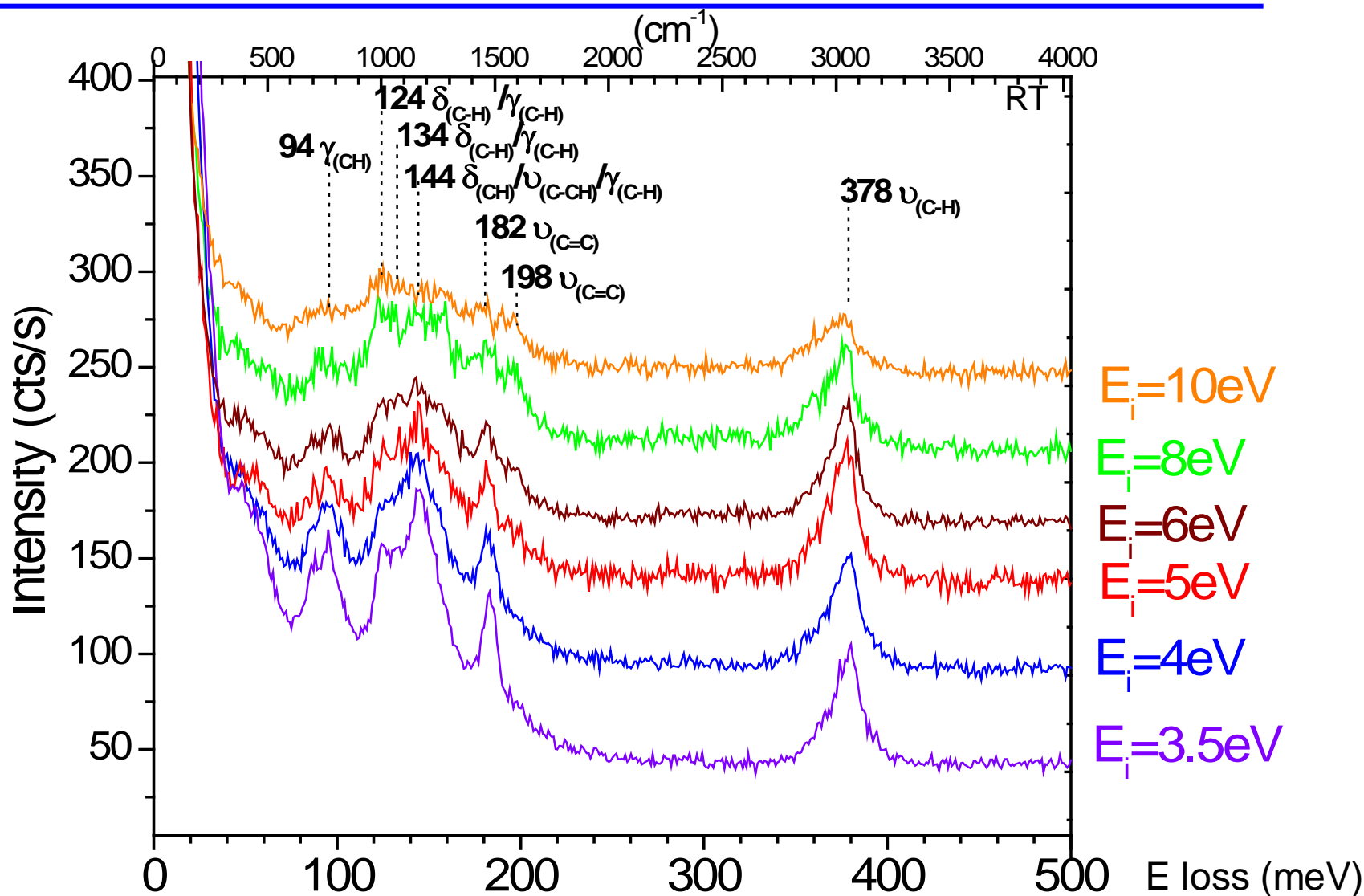
Supported layer CHARACTERIZATION by vibrational spectroscopy

High Resolution Electron Energy Loss Spectroscopy (HREELS)

Energy Loss spectra  $I = I_{E_0}(\Delta E)$  & Excitation functions  $I = I_{\Delta E}(E_0)$



# TPT – Vibrational excitation



Assignments: Barnes Surf. Rev. Lett. 1999; Shen Surf. Sci. 1993; Arnold Langmuir  
 COLDBEAMS, Nîmes, October 2012 2001; Shaporenko J. Phys. Chem. 2004



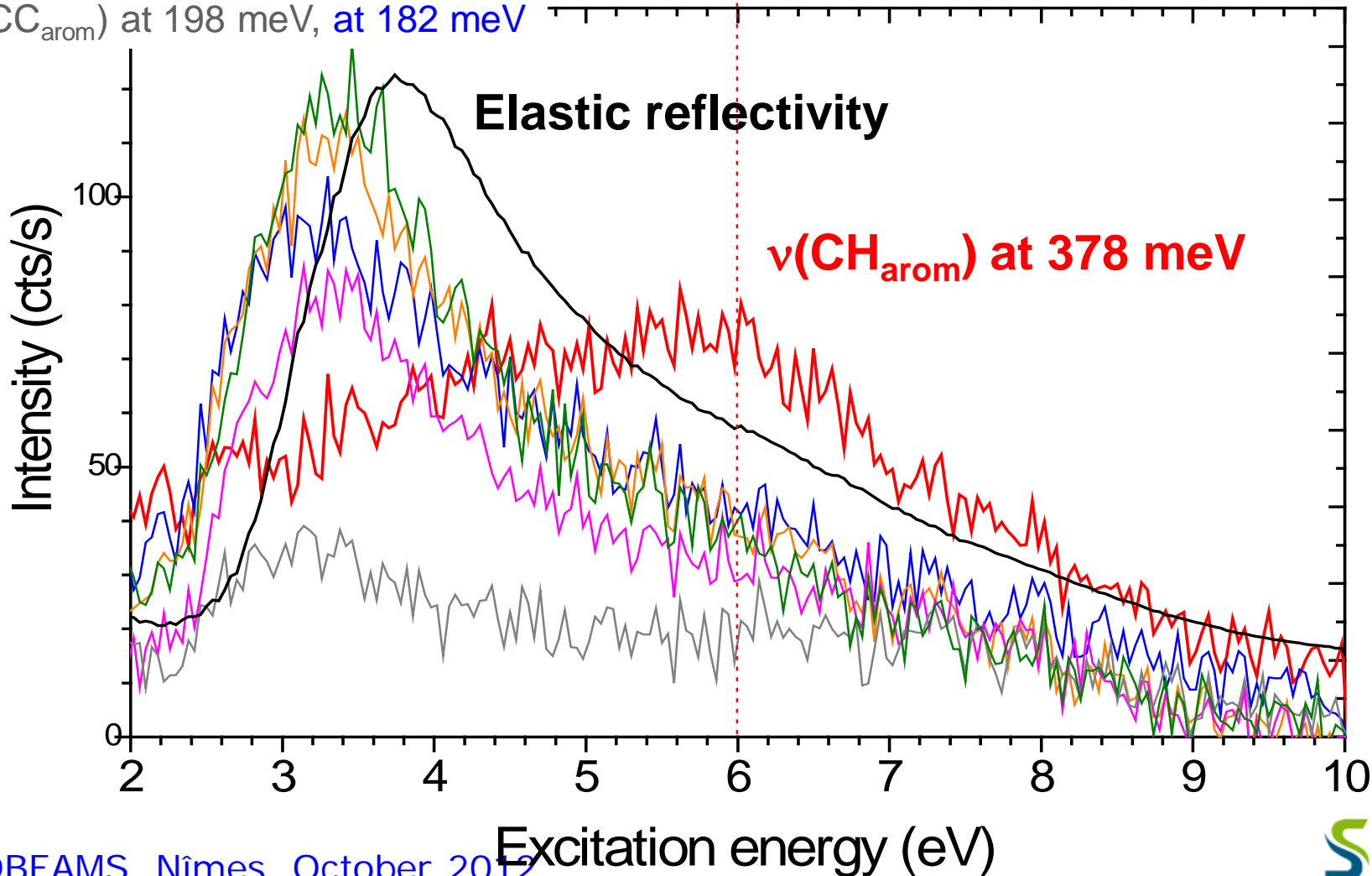
# TPT- Selective resonance at 6 eV for $\nu(\text{CH}_{\text{arom}})$

$\gamma(\text{CH}_{\text{arom}})$  at 94 meV

$\delta(\text{CH}_{\text{arom}}) / \gamma(\text{CH}_{\text{arom}})$  at 124 meV

$\delta(\text{CH}_{\text{arom}}) / \nu(\text{C-CH}) / \gamma(\text{CH}_{\text{arom}})$  at 144 meV

$\nu(\text{CC}_{\text{arom}})$  at 198 meV, at 182 meV



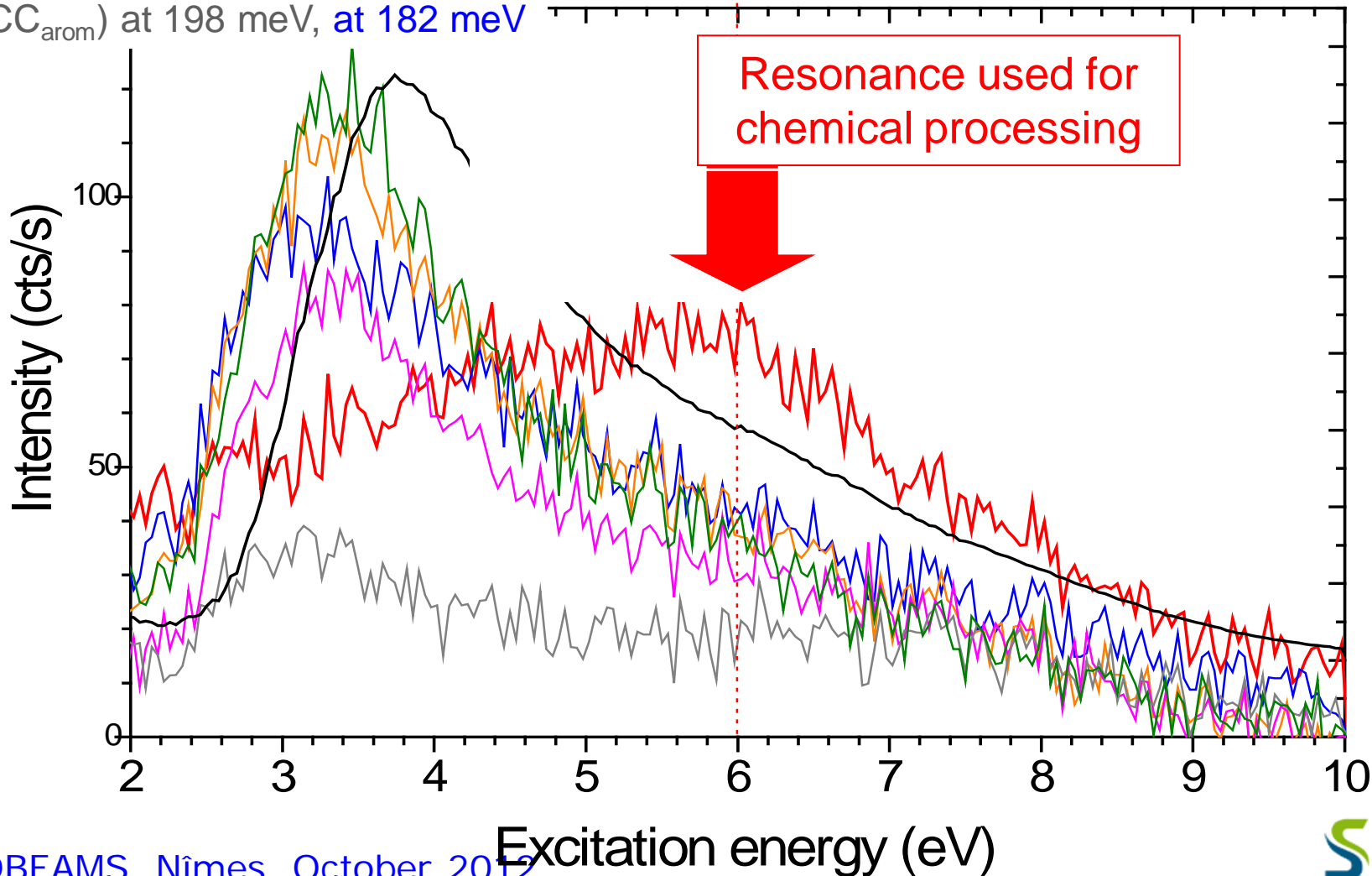
# TPT- Selective resonance at 6 eV for $\nu(\text{CH}_{\text{arom}})$

$\gamma(\text{CH}_{\text{arom}})$  at 94 meV

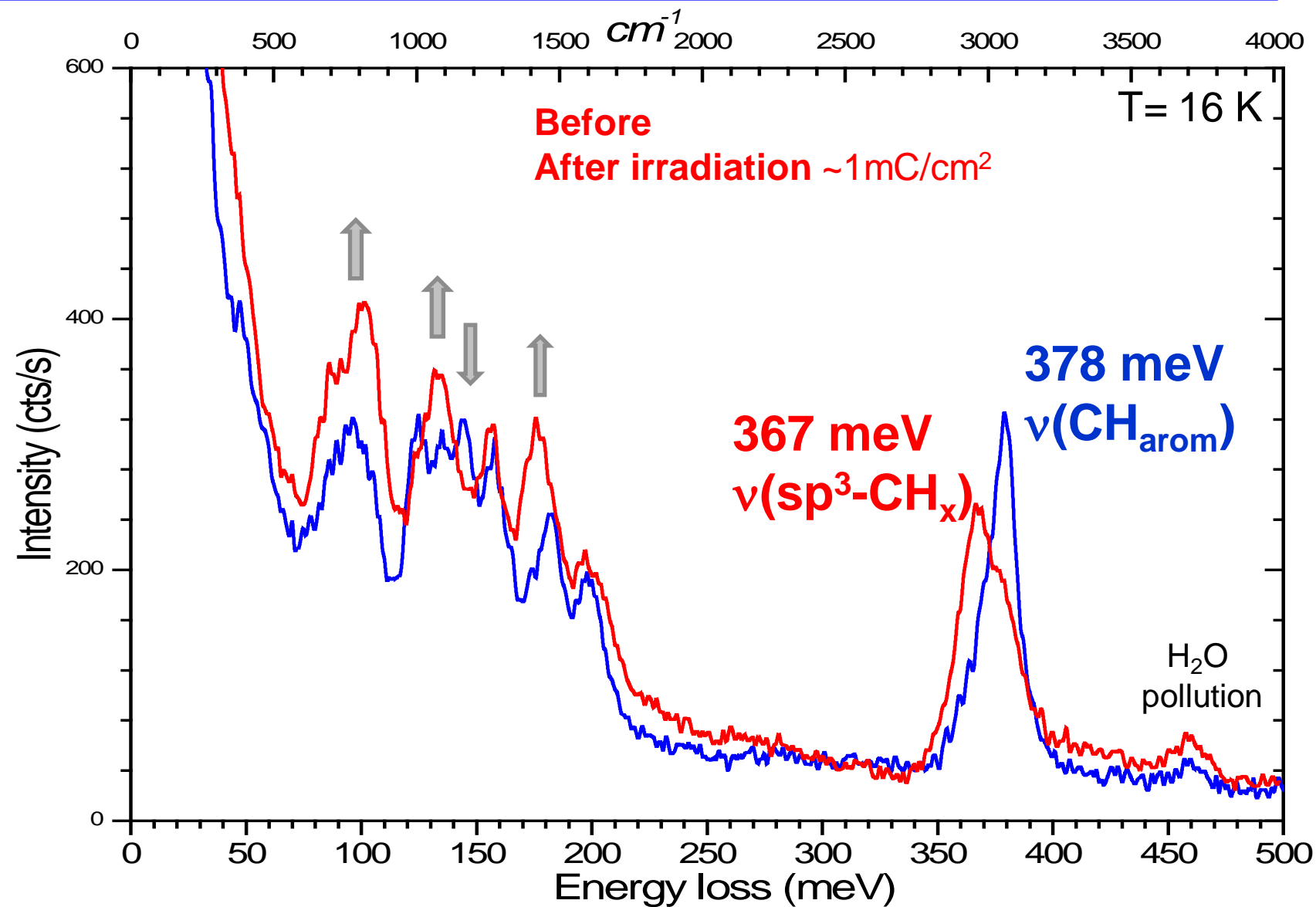
$\delta(\text{CH}_{\text{arom}}) / \gamma(\text{CH}_{\text{arom}})$  at 124 meV

$\delta(\text{CH}_{\text{arom}}) / \nu(\text{C-CH}) / \gamma(\text{CH}_{\text{arom}})$  at 144 meV

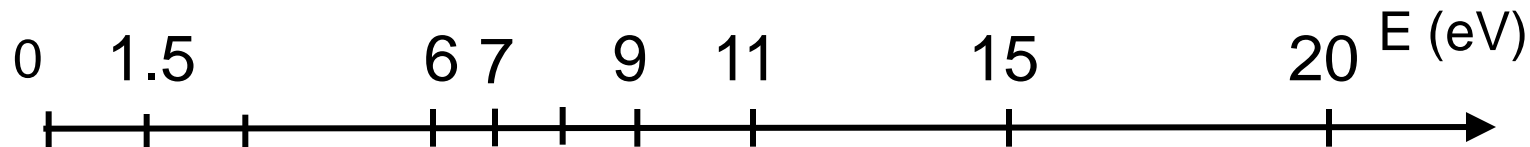
$\nu(\text{CC}_{\text{arom}})$  at 198 meV, at 182 meV



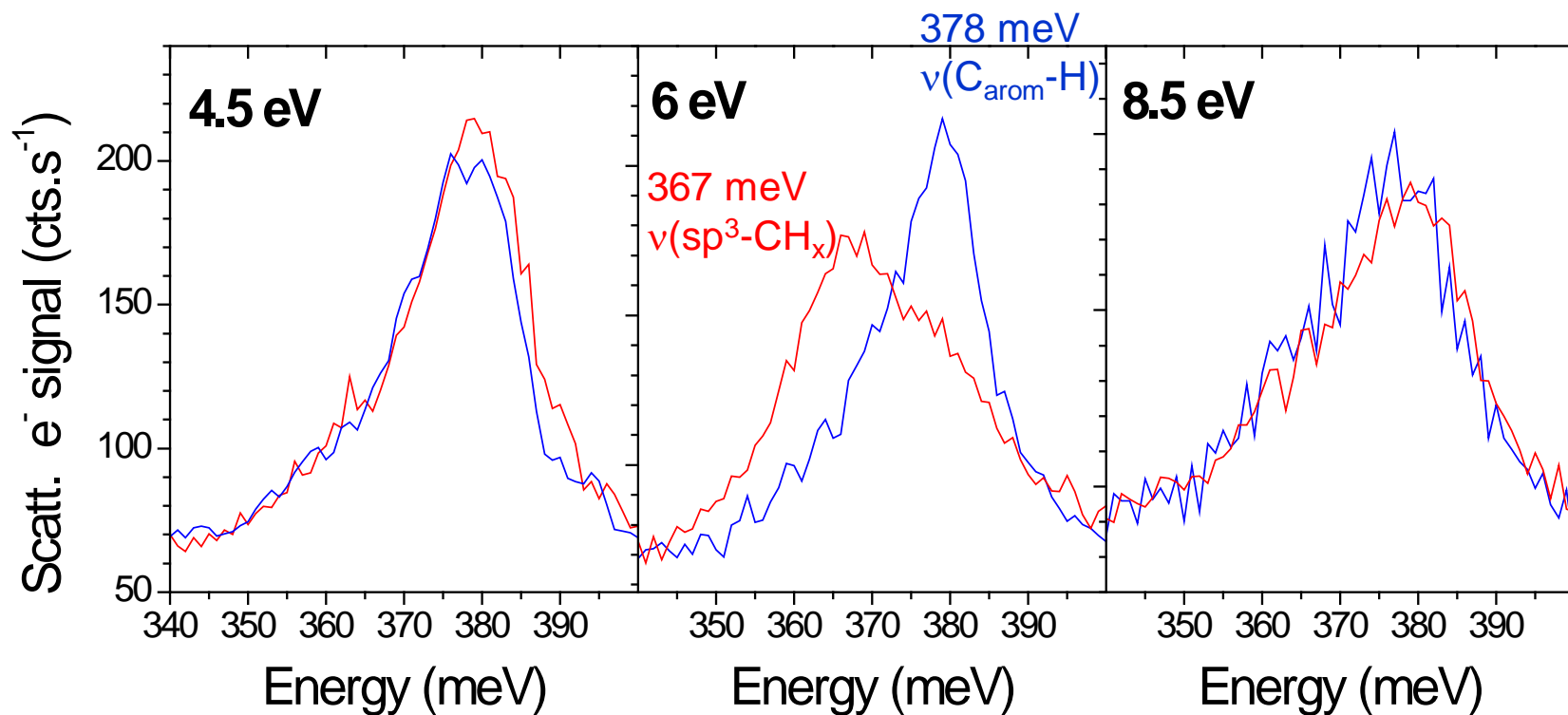
# TPT – e<sup>-</sup> induced loss of aromaticity at 6 eV



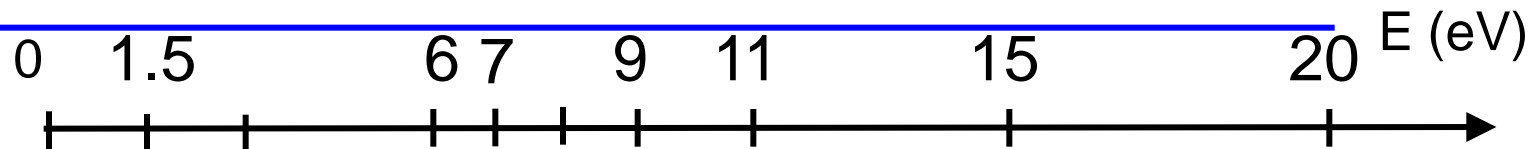
# TPT - Irradiation energy effect on the induced chemistry



Aromatic



# Involved processes and proposed mechanism

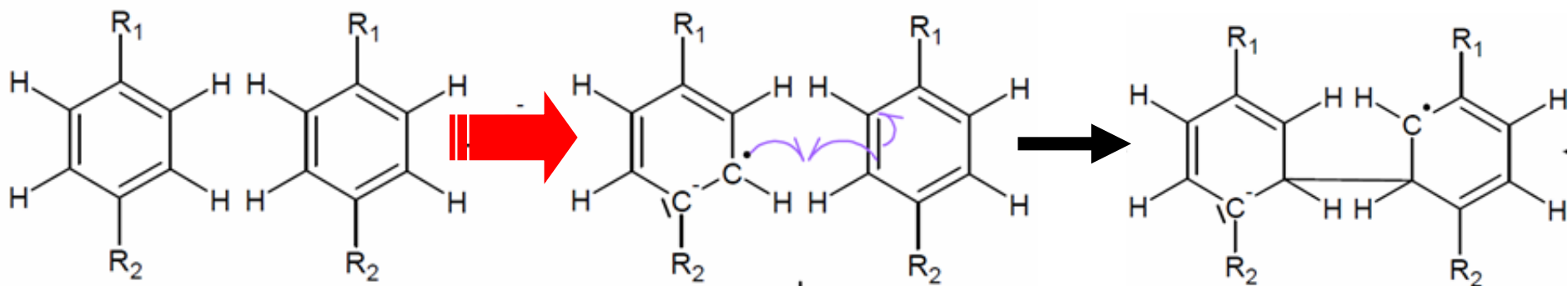


(D)EA ~ ionization

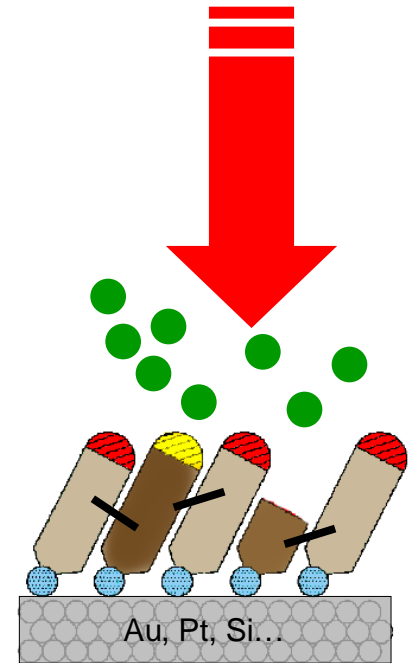
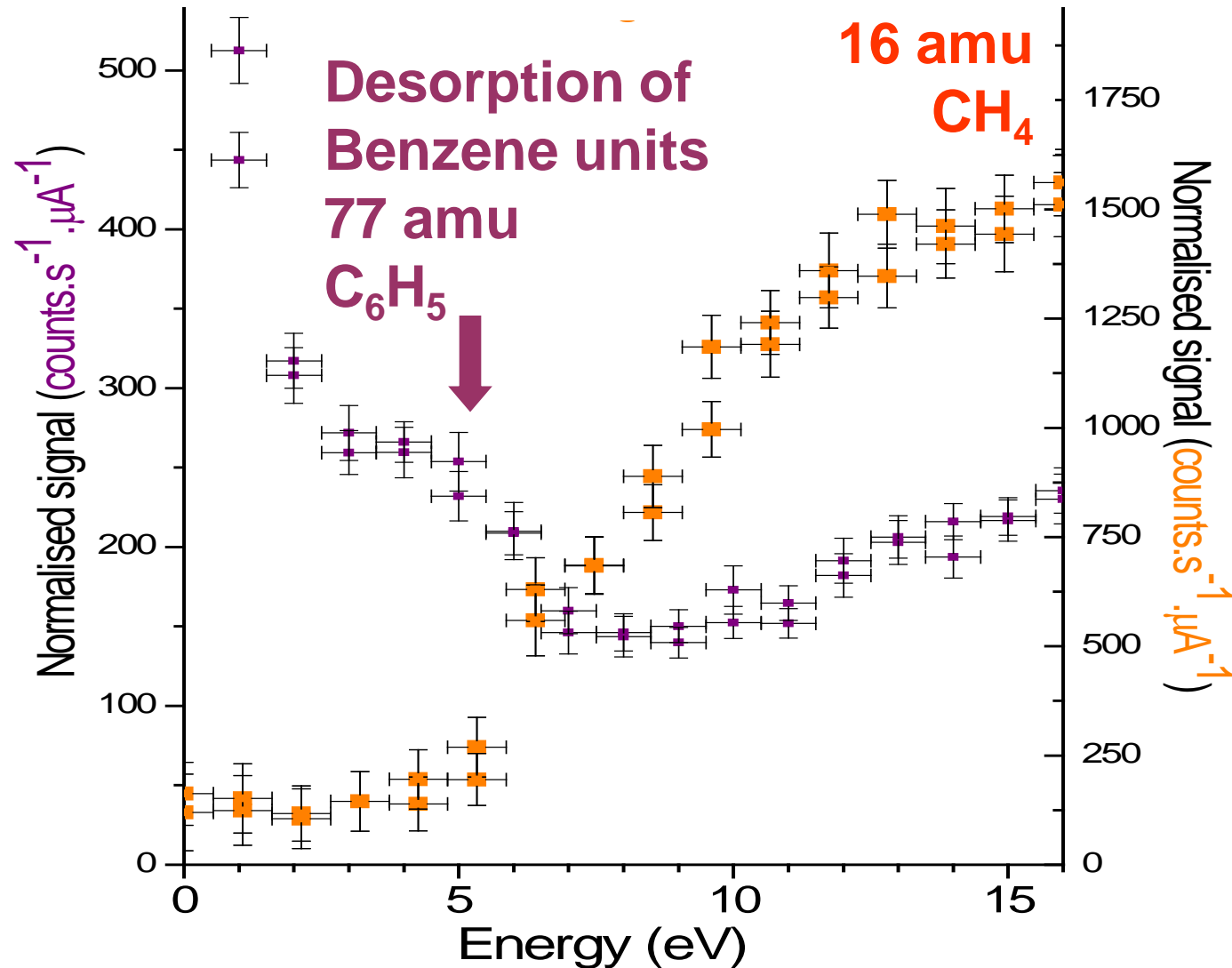
Enhanced vibrational excitation  
Aromaticity loss -  $\text{CH}_{\text{arom}} \rightarrow \text{sp}^3\text{-CH}_x$  conversion

## Proposed contributing mechanism

Low-energy electron attachment  $\rightarrow$  formation of an activated site (radical)  
 $\rightarrow$  radical induced loss of aromaticity  $\rightarrow$  cross linking



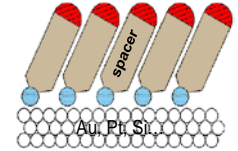
# Preliminary results - ESD of neutral fragments (QMS)



# Conclusion & perspectives

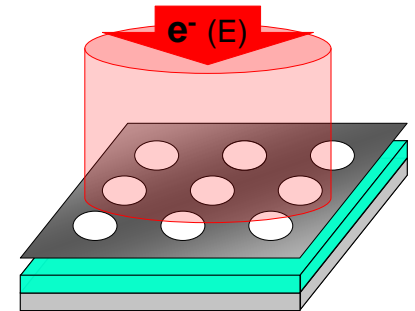
Low-energy (0-20 eV) electron processing of supported thin films studied by vibrational spectroscopy (HREELS) & ESD

- To identify some induced chemical modifications
- To understand the processes induced by low-energy electrons



Development of irradiation strategies using low-energy electrons as processing particles

- Chemical control achieved through DEA
- Towards 2D structuring at the micrometer scale using scale using masks, at the nanometer-scale using new low-energy electron beams...



Collaboration with Daniel Comparat's group (LAC)

Monochromatic electron source based on a Cs 2D-Magneto Optical Trap (MOT)

cf. Yoann Bruneau 's talk and Guyve Khalili 's poster



# Thanks

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## Thank you for your attention

V. Humblot, C.-M. Pradier

Laboratoire de réactivité de surface

Université Pierre & Marie Curie – CNRS, Paris

